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Diodes Incorporated DMP1080UCB4-7

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Datasheet of DMP1080UCB4-7 - MOSFET P-CH 12V U-WLB1010-4

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DMP1080UCB4

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary (Typ. @ $V_{GS} = -4.5V$, $T_A = +25^{\circ}C$)

V _{DSS}	R _{DS(on)}	Qg	Q_{gd}	l _D
-12V	65mΩ	2.5nC	0.6nC	-3.3A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Management
- Load Switch
- Battery Protection

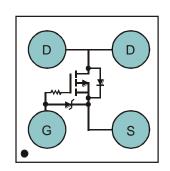
Features

- LD-MOS Technology with the Lowest Figure of Merit: $R_{DS(on)} = 65 m\Omega \text{ to Minimize On-State Losses}$
 - Q_g = 2.5nC for Ultra-Fast Switching $V_{qs(th)}$ = -0.6V typ. for a Low Turn-On Potential
- CSP with Footprint 1.0mm × 1.0mm
- Height = 0.62mm for Low Profile
- ESD = 3kV HBM Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: U-WLB1010-4
- Terminal Connections: See Diagram Below
- Weight: 0.0018 grams (Approximate)

U-WLB1010-4



Top View Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP1080UCB4-7	U-WLB1010-4	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

U-WLB1010-4



BW = Product Type Marking Code YM = Date Code Marking Y = Year (ex: X = 2010)

M = Month (ex: 9 = September)

Date Code Key

Year	201	1	2012		2013	20	14	2015		2016	2	2017
Code	Υ		Z		Α	l l	3	С		D		E
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	-12	V		
Gate-Source Voltage			V_{GSS}	-6	V
Continuous Drain Current (Note 5) V _{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	I _D	-3.3 -2.7	Α
Continuous Drain Current (Note 5) V _{GS} = -2.5V	Steady State	T _A = +25°C T _A = +70°C	I _D	-3.0 -2.4	Α
Pulsed Drain Current (Note 6)	I _{DM}	20	Α		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	P _D	0.82	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 7)	$R_{\theta JA}$	150	°C/W
Thermal Resistance, Junction to Case @T _C = +25°C (Note 7)	R ₀ JC	42.66	°C/W
Power Dissipation (Note 5)	P _D	1.59	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	$R_{\theta JA}$	80.29	°C/W
Operating and Storage Temperature Range	T_{J}, T_{STG}	-55 to +150	°C

Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	-12	-	-	V	$V_{GS} = 0V, I_D = -250\mu A$	
Gate-Source Breakdown Voltage	BV _{GSS}	-6.0	-	-	V	$V_{DS} = 0V, I_{G} = -250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	-	-	-1	μΑ	$V_{DS} = -9.6V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	-100	nA	$V_{GS} = -6V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	-0.4	-0.6	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
		•	65	80		$V_{GS} = -4.5V, I_D = -500mA$	
Static Drain-Source On-Resistance	R _{DS} (ON)	-	77	93	$m\Omega$	$V_{GS} = -2.5V, I_D = -500mA$	
		-	108	130		$V_{GS} = -1.5V, I_D = -500mA$	
Forward Transfer Admittance	Y _{fs}	-	4	-	S	$V_{DS} = -6V, I_{D} = -500mA$	
Diode Forward Voltage	V_{SD}		-0.6	-1.0	V	$V_{GS} = 0V, I_S = -500mA$	
Reverse Recovery Charge	Qrr	-	2.0	-	nC	$V_{dd} = -4.0V, I_F = -0.5A,$	
Reverse Recovery Time	t _{rr}	-	9.5	-	ns	di/dt =100A/μs	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	-	213	350		.,	
Output Capacitance	Coss	-	119	250	pF	$V_{DS} = -6V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	54.4	90		1 - 1.01/11 12	
Total Gate Charge	Qg	-	2.5	5			
Gate-Source Charge	Qgs	-	0.3	-	nC	$V_{GS} = -4.5V, V_{DS} = -6V,$	
Gate-Drain Charge	Q_{gd}	-	0.6	-	nc	$I_D = -500 \text{mA}$	
Gate Charge at Vth	Q _{q(th)}	-	0.15	-			
Turn-On Delay Time	t _{D(on)}	-	16.7	-			
Turn-On Rise Time	t _r	-	20.6	-		$V_{DS} = -6V, V_{GS} = -2.5V,$	
Turn-Off Delay Time	t _{D(off)}	-	38.4	-	ns	$R_G = 20\Omega, I_D = -500 \text{mA}$	
Turn-Off Fall Time	t _f	-	28.4	-			

Notes:

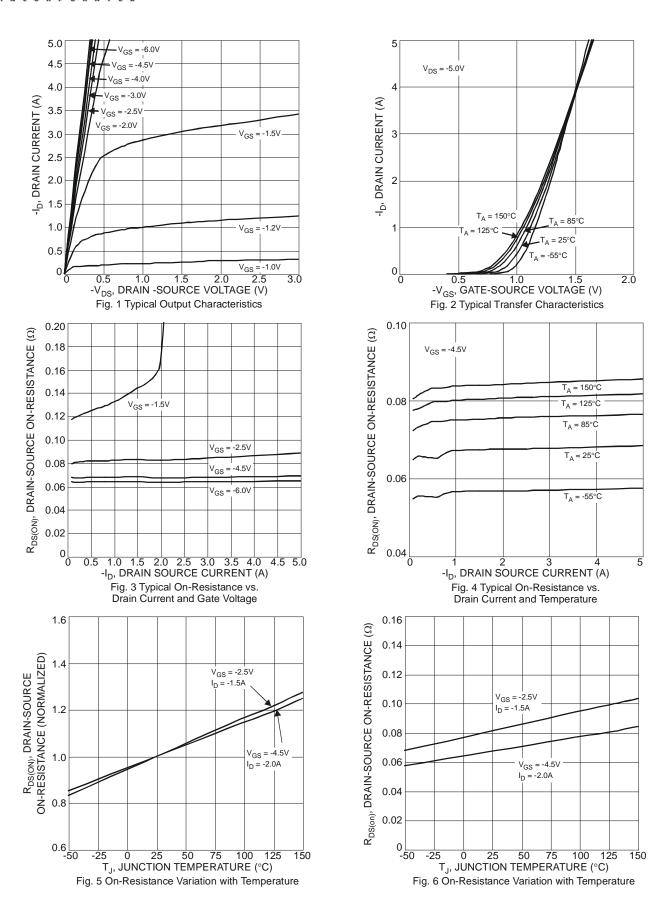
- 5. Device mounted on FR4 material with 1-inch 2 (6.45-cm 2), 2-oz. (0.071-mm thick) Cu.
- Repetitive rating, pulse width limited by junction temperature.
 Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to production testing.

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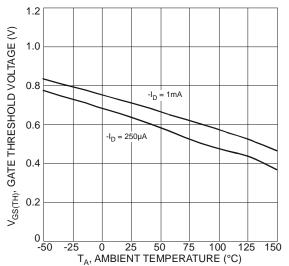
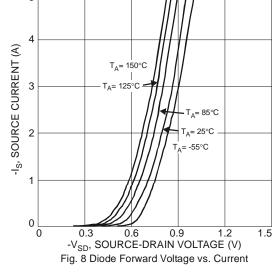


Fig. 7 Gate Threshold Variation vs. Ambient Temperature



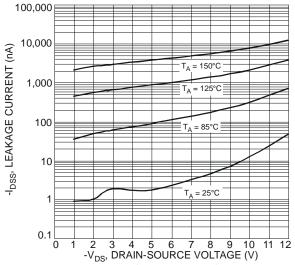
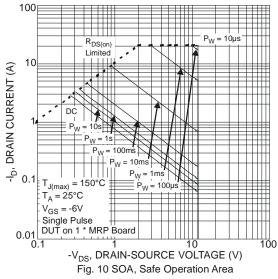
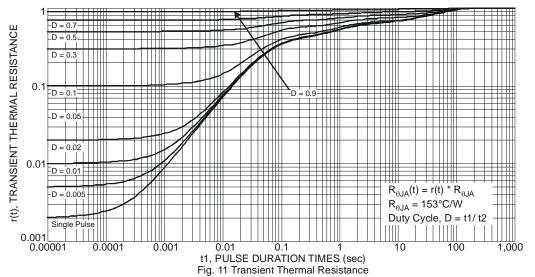


Fig. 9 Typical Drain-Source Leakage Current vs. Voltage





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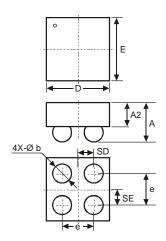
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Package Outline Dimension

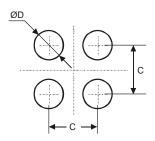
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



U-WLB1010-4						
Dim	Min	Max	Тур			
D	0.95	1.05	1.00			
Е	0.95	1.05	1.00			
Α	_	0.62	_			
A2	_	_	0.38			
b	0.25	0.35	0.30			
е	-	-	0.50			
SD	_	_	0.25			
SE	_	_	0.25			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.50
D	0.25



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